

MOSFET – Power, Single N-Channel, DFN5/DFNW5

40 V, 3.7 mΩ, 87 A NVMFS5C456NL

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFS5C456NLWF Wettable Flank Option for Enhanced Optical Inspection
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25 °C unless otherwise noted)

Symbol	Parameter		Value	Unit	
V _{DSS}	Drain-to-Source Voltage			40	V
V _{GS}	Gate-to-Source Volta	ıge		±20	V
I _D	Continuous Drain Current R _{0.IC}		T _C = 25 °C	87	Α
	(Notes 1, 3)	Stead v	T _C = 100 °C	61	
P _D	Power Dissipation	State	T _C = 25 °C	55	W
	R _{θJC} (Note 1)		T _C = 100 °C	27	
I _D	Continuous Drain		T _A = 25 °C	22	Α
	Current R _{0JA} (Notes 1, 2, 3)	Stead v	T _A = 100 °C	16	
P_{D}	Power Dissipation	State	T _A = 25 °C	3.6	W
	R _{θJA} (Notes 1 & 2)		T _A = 100 °C	1.8	
I _{DM}	Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	520	Α
T _J , T _{stg}	Operating Junction and Storage Temperature		–55 to + 175	°C	
I _S	Source Current (Body Diode)			61	Α
E _{AS}	Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 5 A)			202	mJ
TL	Lead Temperature fo (1/8" from case for 10		g Purposes	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$R_{ heta JC}$	Junction-to-Case - Steady State	2.7	°C/
$R_{ heta JA}$	Junction-to-Ambient - Steady State (Note 2)	42	W

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
- Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

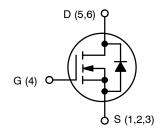
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX	
40 V	3.7 m Ω @ 10 V	87 A	
40 V	6.0 mΩ @ 4.5 V	87 A	





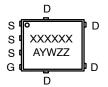


DFNW5 CASE 507BE



N-CHANNEL MOSFET

MARKING DIAGRAM



XXXXXX = 5C456L

(NVMFS5C456NL) or

456LWF

(NVMFS5C456NLWF)

= Assembly Location

Y = Year W = Work

Work WeekLot Traceability

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

ELECTRICAL CHARACTERISTICS ($T_J = 25 \, ^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Cond	ition	Min	Тур	Max	Unit	
OFF CHAR	ACTERISTICS	•					•	
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	V _{GS} = 0 V, I _D =	= 250 μA	40			V	
V _{(BR)DSS} /	Drain-to-Source Breakdown Voltage Temperature Coefficient				22		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} = 0 V,	T _J = 25 °C			10		
		V _{DS} = 40 V	T _J = 125 °C			250	μΑ	
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS}	_S = 20 V			100	nA	
ON CHARA	CTERISTICS (Note 4)							
V _{GS(TH)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D}$	= 50 μΑ	1.2		2.0	V	
V _{GS(TH)} /T _J	Threshold Temperature Coefficient				-5.1		mV/°C	
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 4.5 V	I _D = 20 A		4.8	6.0		
		V _{GS} = 10 V	I _D = 20 A		3.1	3.7	mΩ	
9FS	Forward Transconductance	V _{DS} =15 V, I _D	= 40 A		80		S	
CHARGES,	CAPACITANCES & GATE RESISTANCE							
C _{ISS}	Input Capacitance				1600			
C _{OSS}	Output Capacitance	V _{GS} = 0 V, f = 1 MH.	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 25 V		590		pF	
C _{RSS}	Reverse Transfer Capacitance				21		1	
Q _{G(TOT)}	Total Gate Charge	V _{GS} = 10 V, V _{DS} = 2	0 V; I _D = 40 A		18		nC	
Q _{G(TOT)}	Total Gate Charge				8.2			
Q _{G(TH)}	Threshold Gate Charge		V _{GS} = 4.5 V, V _{DS} = 20 V; I _D = 40 A		2		nC	
Q_{GS}	Gate-to-Source Charge	V _{GS} = 4.5 V, V _{DS} = 2			3.8			
Q_{GD}	Gate-to-Drain Charge				2.1		1	
V _{GP}	Plateau Voltage				3.2		V	
SWITCHING	CHARACTERISTICS (Note 5)							
t _{d(ON)}	Turn-On Delay Time				13			
t _r	Rise Time	V _{GS} = 4.5 V, V _D	_{os} = 20 V,		54		1	
t _{d(OFF)}	Turn-Off Delay Time	I _D = 30 A, R _G	$_{3}=1~\Omega$		34		ns	
t _f	Fall Time				10		1	
DRAIN-SOL	URCE DIODE CHARACTERISTICS							
V _{SD}	Forward Diode Voltage	V _{GS} = 0 V,	T _J = 25 °C		0.86	1.2		
		I _S = 40 A	T _J = 125 °C		0.75			
t _{RR}	Reverse Recovery Time				29			
t _a	Charge Time	$V_{GS} = 0 \text{ V, dI}_S/\text{dt}$	= 100 A/us.		14		ns	
t _b	Discharge Time	$I_{S} = 40$			15			
Q _{RR}	Reverse Recovery Charge		┥		20		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.



TYPICAL CHARACTERISTICS

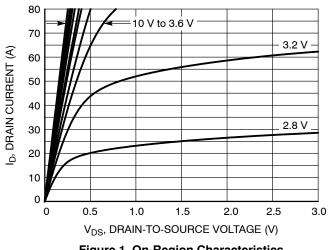


Figure 1. On-Region Characteristics

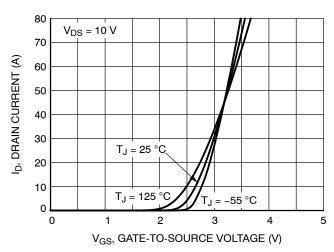


Figure 2. Transfer Characteristics

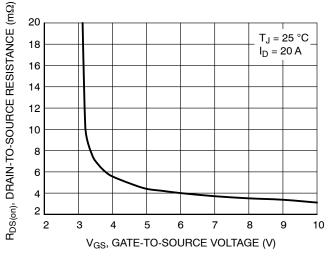


Figure 3. On-Resistance vs. Gate-to-Source Voltage

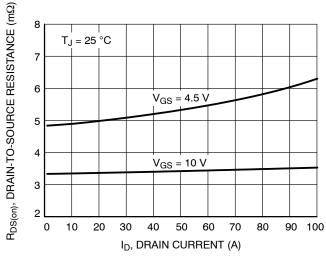


Figure 4. On-Resistance vs. Drain Current and **Gate Voltage**

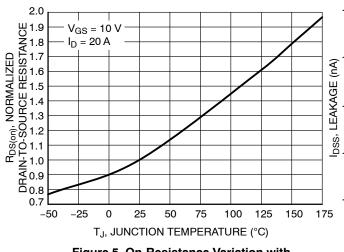


Figure 5. On-Resistance Variation with **Temperature**

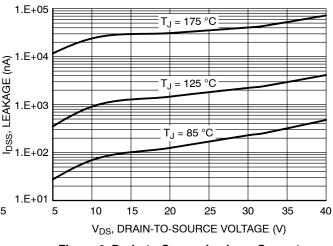


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS (continued)

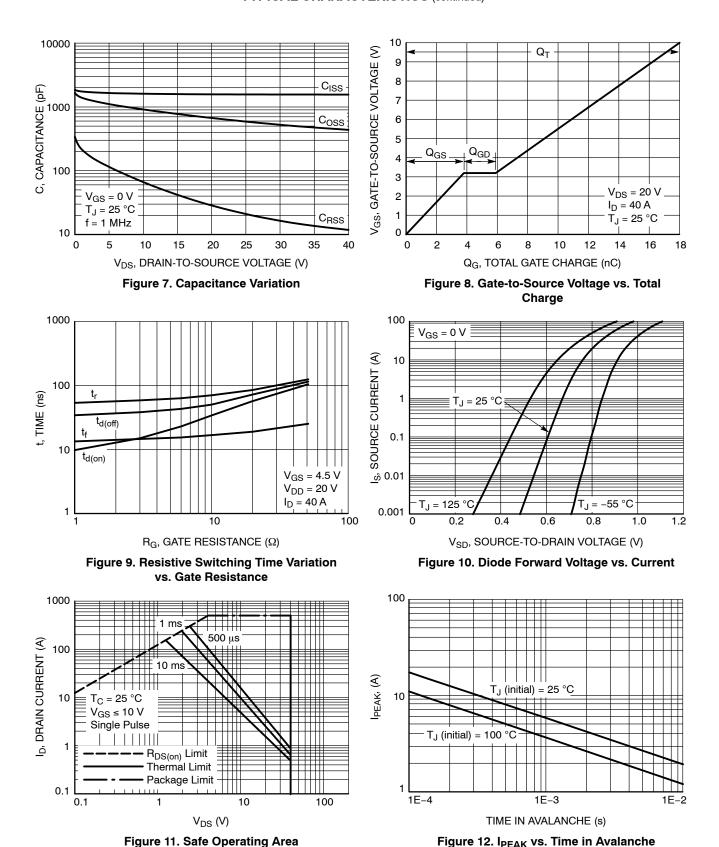


Figure 12. I_{PEAK} vs. Time in Avalanche

TYPICAL CHARACTERISTICS (continued)

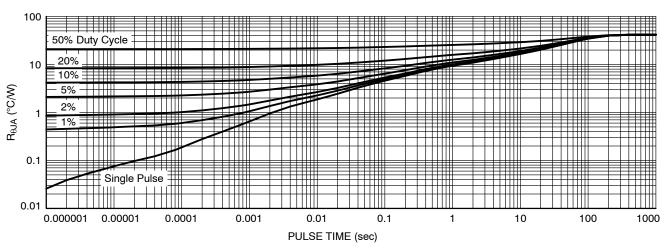


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS5C456NLET1G-YE	5C456L	DFN5 (Pb-Free)	1,500 / Tape & Reel
NVMFS5C456NLT1G	5C456L	DFN5 (Pb-Free)	1,500 / Tape & Reel
NVMFS5C456NLT3G	5C456L	DFN5 (Pb-Free)	5,000 / Tape & Reel
NVMFS5C456NLAFT1G	5C456L	DFN5 (Pb-Free)	1,500 / Tape & Reel
NVMFS5C456NLAFT1G-YE	5C456L	DFN5 (Pb-Free)	1,500 / Tape & Reel
NVMFS5C456NLWFAFT1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1,500 / Tape & Reel
NVMFS5C456NLWFET1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1,500 / Tape & Reel
NVMFS5C456NLWFET3G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	5,000 / Tape & Reel

DISCONTINUED (Note 6)

NVMFS5C456NLWFT1G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	1,500 / Tape & Reel
NVMFS5C456NLWFT3G	456LWF	DFNW5 (Pb-Free, Wettable Flanks)	5,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{6.} **DISCONTINUED:** These devices are not available. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

REVISION HISTORY

Revision	Revision Description of Changes	
11	NVMFS5C456NLWFT1G, NVMFS5C456NLWFT3G OPN's Marked as Discontinued.	7/16/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.





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SIDE VIEW

DFN5 5x6, 1.27P (SO-8FL) CASE 488AA **ISSUE N**

DATE 25 JUN 2018

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION D1 AND E1 DO NOT INCLUDE
- MOLD FLASH PROTRUSIONS OR GATE BURRS

	MILLIMETERS			
DIM	MIN NOM MAX			
Α	0.90	1.00	1.10	
A1	0.00		0.05	
b	0.33	0.41	0.51	
С	0.23	0.28	0.33	
D	5.00	5.15	5.30	
D1	4.70 4.90		5.10	
D2	3.80	4.00	4.20	
E	6.00	6.15	6.30	
E1	5.70	5.90	6.10	
E2	3.45	3.65	3.85	
е		1.27 BSC)	
G	0.51	0.575	0.71	
K	1.20	1.35	1.50	
L	0.51	0.575	0.71	
L1	0.125 REF			
М	3.00 3.40 3.8		3.80	
θ	θ 0 ° 12		12 °	

GENERIC MARKING DIAGRAM*

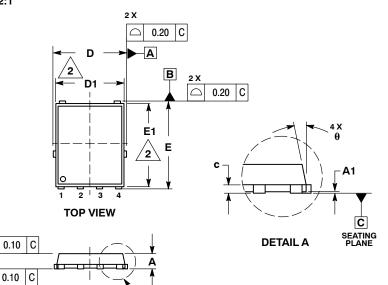


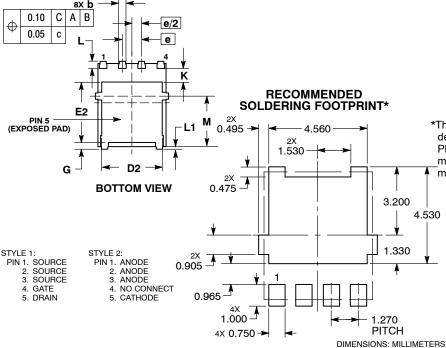
XXXXXX = Specific Device Code

= Assembly Location Α

Υ = Year W = Work Week ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.





DETAIL A

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

	DOCUMENT NUMBER:	98AON14036D	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
ſ	DESCRIPTION:	DFN5 5x6, 1.27P (SO-8FL)		PAGE 1 OF 1	

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PIN 1

IDENTIFIER

// 0.10 C

△ 0.10 C

DFNW5 4.90x5.90x1.00, 1.27P

CASE 507BE **ISSUE B**

DATE 19 SEP 2024

MAX

1.10

0.05

0.51

0.33

5.30

5.10

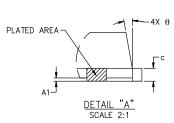
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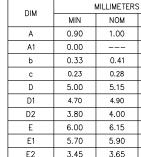
6.30

6.10

NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M-2018. 1.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
- THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.



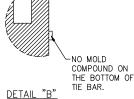




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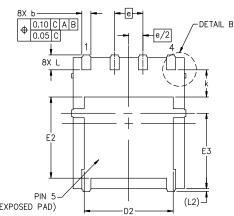
CONSTRUCTION



3.85 E3 3.40 3.00 3.80 1.27 BSC е 1.20 1.35 1.50 L 0.51 0.57 0.71 L2 0.15 REF. 12°

6°

0.



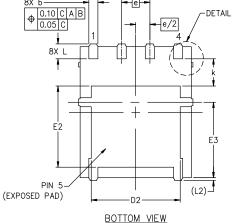
TOP VIEW

DETAIL A

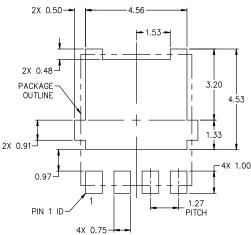
SIDE VIEW

SEATING

PLANE



SCALE 2:1



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RECOMMENDED MOUNTING FOOTPRINT* *FOR ADDITIONAL INFORMATION ON OUR Pb—FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Assembly Location Α Υ = Year

W = Work Week 77 = Lot Traceability

XXXXXX = Specific Device Code *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION: DFNW5 4.90x5.90x1.00, 1.27P **PAGE 1 OF 1**

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